



4A TrenchSBR TRENCH SUPER BARRIER RECTIFIER

Product Summary (@T_A = +25°C)

V _{RRM} (V)	I _O (A)	V _F MAX (V)	I _{R MAX} (μ A)
30	4	0.51	60

Description and Applications

The SBRT4M30LP is a 4A, 30V single rectifier packaged in the low profile DFN3030 package. Providing low VF and excellent high temperature stability, this device is ideal for use in general rectification applications such as:

- Bypass Diode
- Boost Diode
- Blocking Diode
- Recirculating Diode

Features and Benefits

- Reduced ultra-low forward voltage drop (V_F); Better efficiency and cooler operation.
- Reduced high temperature reverse leakage; Increased reliability against thermal runaway failure in high temperature operation.
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)

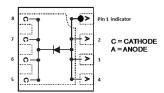
Mechanical Data

- Case: U-DFN3030-8
- Case Material: Molded Plastic, "Green" Molding Compound;
 UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish NiPdAu Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208
- Weight: 0.0172 grams (Approximate)

U-DFN3030-8



Bottom View



Top View Schematic and Pin Configuration

Ordering Information (Note 4)

F	Part Number	Qualification	Case	Packaging
	SBRT4M30LP-7	Commercial	U-DFN3030-8	3,000/Tape & Reel

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- 2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

Marking Information

U-DFN3030-8



T4M30 = Product Type Marking Code YYWW = Date Code Marking Y Y= Last Two Digits of Year (ex: 15 for 2015) WW = Week Code 01 to 53



Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Single phase, half wave, 60Hz, resistive or inductive load. For capacitance load, derate current by 20%.

Characteristic	Symbol	Value	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _{RM}	30	V
Average Rectified Output Current	Io	4	Α
Non-Repetitive Peak Forward Surge Current 8.3ms Single Half Sine-Wave Superimposed on Rated Load	I _{FSM}	40	Α

Thermal Characteristics

Characteristic	Symbol	Value	Unit
Typical Thermal Resistance Junction to Ambient (Note 5)	$R_{\theta JA}$	148	°C/W
Typical Thermal Resistance Junction to Case (Note 5)	$R_{ heta JC}$	25	°C/W
Typical Thermal Resistance Junction to Ambient (Note 6)	$R_{ heta JA}$	72	°C/W
Typical Thermal Resistance Junction to Case (Note 6)	$R_{ heta JC}$	7	°C/W
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +150	°C

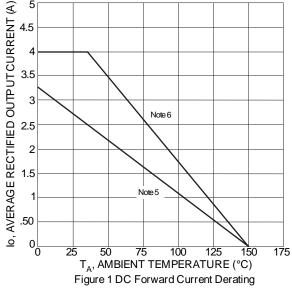
Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

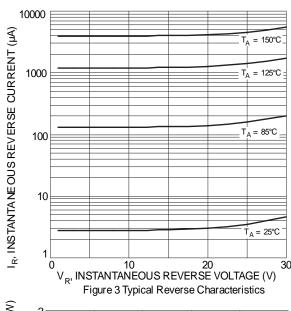
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
			0.43	0.48		I _F = 3A, T _J = +25°C
Forward Voltage Drop	V_{F}	_	_	0.51	V	$I_F = 4A, T_J = +25^{\circ}C$
		_	0.38			I _F = 4A, T _J = +125°C
Leakage Current (Note 7)	-	_	5	60	μA	V _R = 30V, T _J = +25°C
Leakage Current (Note 1)	IR	_	1.7	_	mA	$V_R = 30V, T_J = +125^{\circ}C$
Total Capacitance	Ст	_	150	_	pF	f = 1MHz, VR = 30V
Reverse Recovery Time	Trr		30		ns	IF =0.5A, IR =1.0A, IRR=0.25A

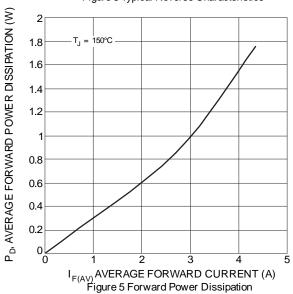
Notes:

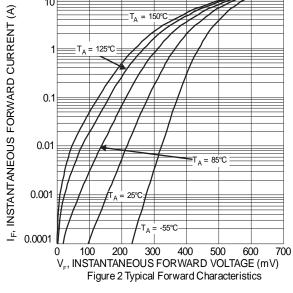
- 5. Test with FR-4 substrate PC board, 2oz copper, 1*MRP.6. Test with PC board, 1-inch sq. copper pad, 2oz.7. Short duration pulse test used to minimize self-heating effect.

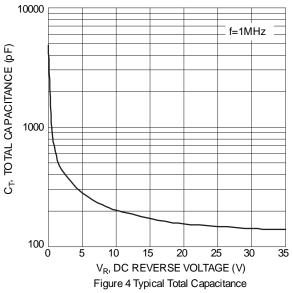








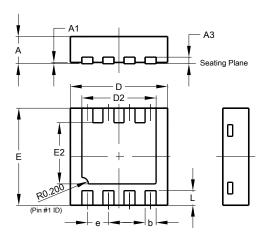






Package Outline Dimensions

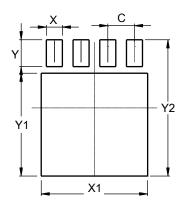
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for the latest version.



U-DFN3030-8				
Dim	Min	Max	Тур	
Α	0.57	0.63	0.60	
A1	0	0.05	0.02	
А3	-	-	0.15	
b	0.29	0.39	0.34	
D	2.90	3.10	3.00	
D2	2.19	2.39	2.29	
е	-	-	0.65	
Е	2.90	3.10	3.00	
E2	1.64	1.84	1.74	
Ĺ	0.30	0.60	0.45	
All Dimensions in mm				

Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value		
Dillielisions	(in mm)		
С	0.650		
Х	0.390		
X1	2.590		
Y	0.650		
Y1	2.490		
V3	3 300		



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